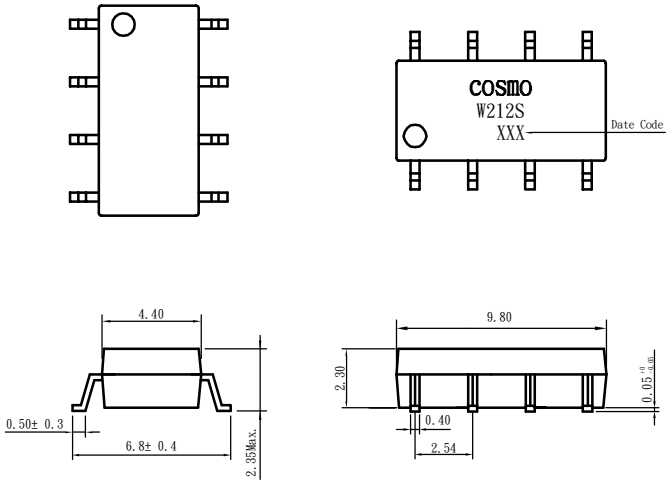
PRODUCT SPECIFICATION

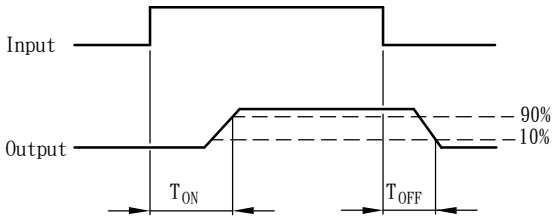
DATE:11/18/2003

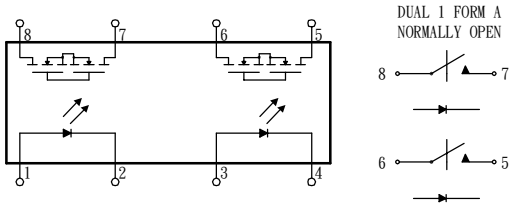
COSMO ELECTRONICS CORPORATION	SOLID STATE RELAY-MOSFET OUTPUT **KAQW212S**	NO. 62M20006	REV.
		SHEET 1 OF 7	1

- OUTSIDE DIMENSION :



- Turn on/Turn off time





Absolute Maximum Ratings (T_A=25° C)

Emitter (Inpute)

Reverse Voltage 5.0V
Continuous Forward Current 50mA
Peak Forward Current (1us) 1A
Power Dissipation. 100mW
Derate Linearly from 25° C . . . . . 1.3mW/° C

Detector (Output)

Output Breakdown Voltage . . . . . ± 60V
Continous Load Current . . . . . ± 400mA
Power Dissipation 500mW

General Characteristics

Isolation Test Voltage. . . . . .1500VAC RMS
Isolation Resistance
V_{IO} =500V, T_A=25° C. . . . . $\geq 10^{10}\Omega$
Total Power Dissipation 550mW

Derate Linearly form 25° C. . . . . .2.5mW/° C
Storage Temperature Range . . . . -40 to +150° C
Operating Temperature Range. . . . -40 to +85° C
Junction Temperature . . . . . .100° C
Soldering Temperature, 2mm from case, 10 sec. 260° C

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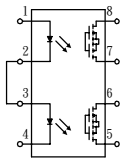
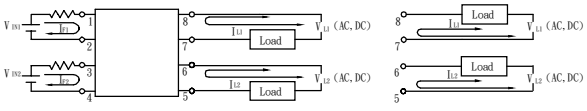
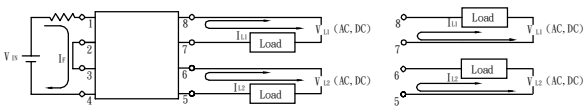
Characteristics (T_A=25° C)

Description	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Emitter (Input)						
Forward Voltage	V_F		1.2	1.5	V	I_F =10mA
Operation Input Current	I_{FON}			5	mA	V_L=± 20V, I_L=100mA, t=10 ms
Recovery Input Current	I_{FOFF}	0.2			mA	V_L=± 20V, I_L=<5uA
Deterctor (Output)						
Output Breakdown Voltage	V_B	60			V	I_B=50uA
Output Off-State Leakage	$I_{T(OFF)}$		0.2	1	uA	V_T=60V, I_F=0mA
I/O Capacitance	C_{ISO}		6		pF	I_F=0, f=1MHz
ON Resistance	R_{ON}		0.83	2.50	Ω	I_L=100mA, I_F=10mA
Turn-on Time	T_{ON}		0.2	1.5	ms	I_F=10mA, V_L=± 20V
Turn-off Time	T_{OFF}		0.3	1.5	ms	t=10ms, I_L=± 100mA

Schematic and Wiring Diagrams

Type	Schematic	Output configur-ation	Load	Con-nection	Wiring diagram
KAQW212S		2a	AC/DC	-	(1)Two independent 1 Form A use  (2) 2 Form A use 

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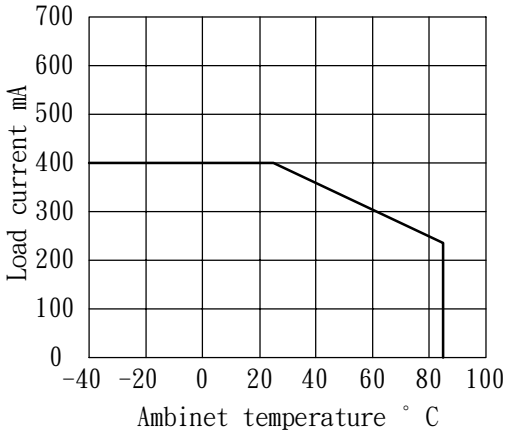
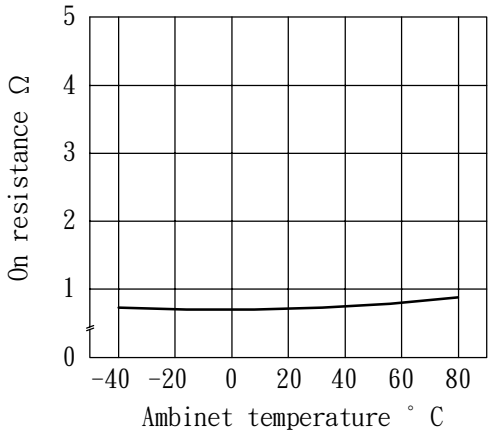
DATA CURVE

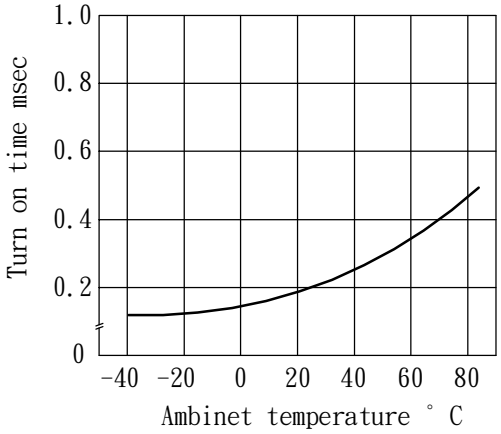
Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +85°C



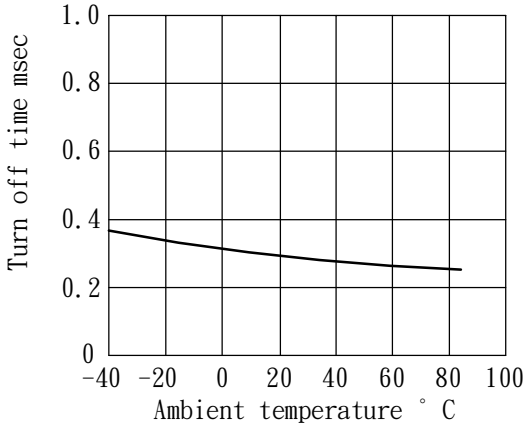
On resistance vs. ambient temperature
Across terminals 5,7 and 6,8 pin
LED current: 5mA
Continuous load current: 130 mA(DC)



Turn on time vs. ambient temperature
Load voltage 60 V(DC)
LED current :5mA
Continuous load current: 130mA(DC)



Turn off time vs. ambient temperature
LED current: 5mA;Load voltage: 60V(DC)
Continuous load current: 130mA(DC)



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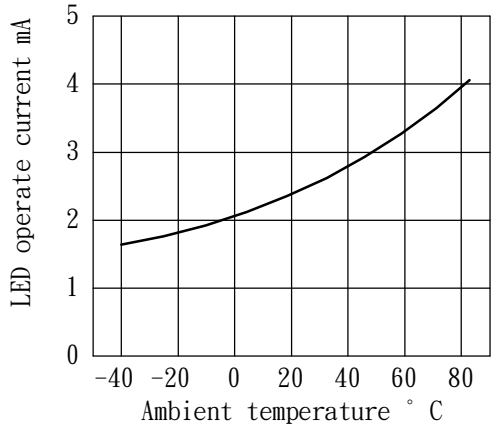
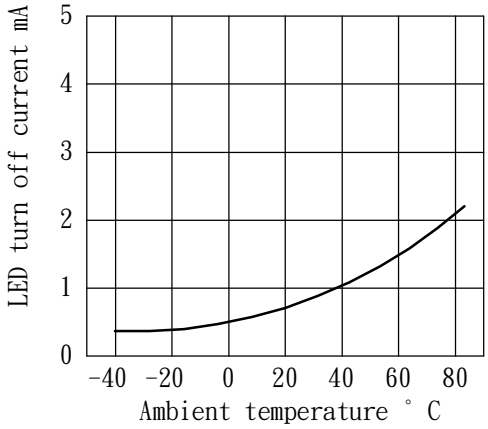
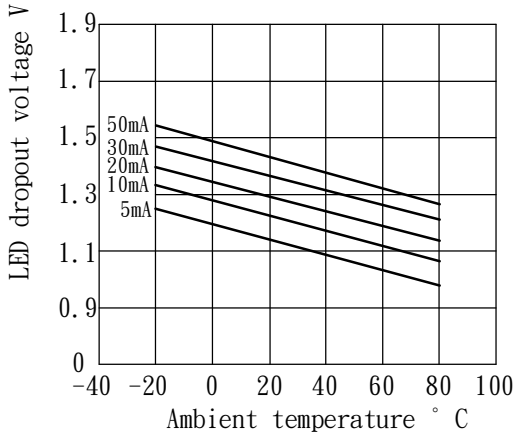
LED operate vs. ambient temperature
Load voltage: 60V(DC)
Continuous load current: 130mA(DC)



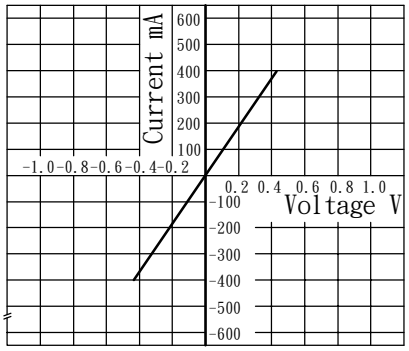
LED turn off current vs. ambient temperature
Load voltage: 60V(DC)
Continuons load current: 130mA(DC)



LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA



Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 5,7 and 6,8 pin
Ambient temperature: 25° C



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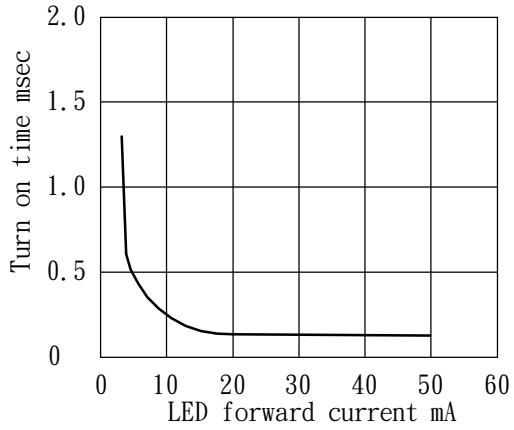
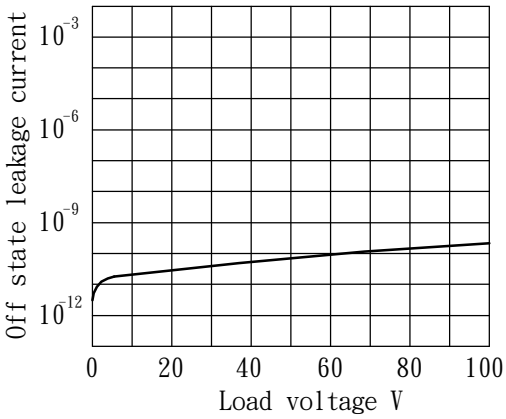
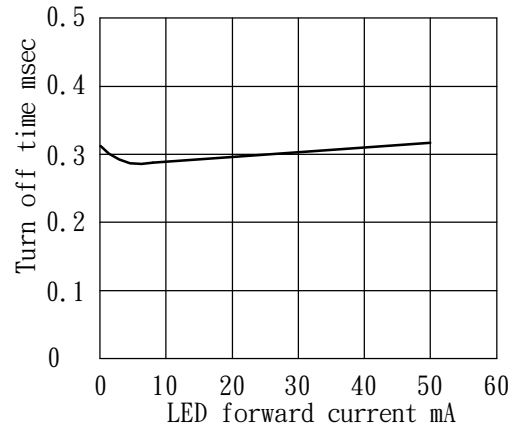
LED forward current vs. turn on time
Across terminals5,7and6,8pin;Load voltage: 60V(DC);Continuous load current :130mA(DC);Ambient temperature: 25° C



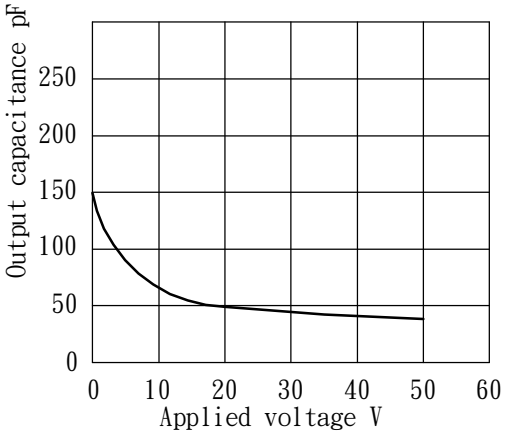
Off state leakage current
Across terminals 5,7 and 6,8 pin
Ambient temperature: 25° C



LED forward current vs. turn off time
Across terminals 5,7and 6,8pin;Load voltage: 60V(DC);Continuous load current: 130 mA(DC);Ambient temperature: 25° C



Applied voltage vs. output capacitance
Across terminals 5,7and 6,8 pin
Frequency: 1MHz;Ambient temperature: 25° C



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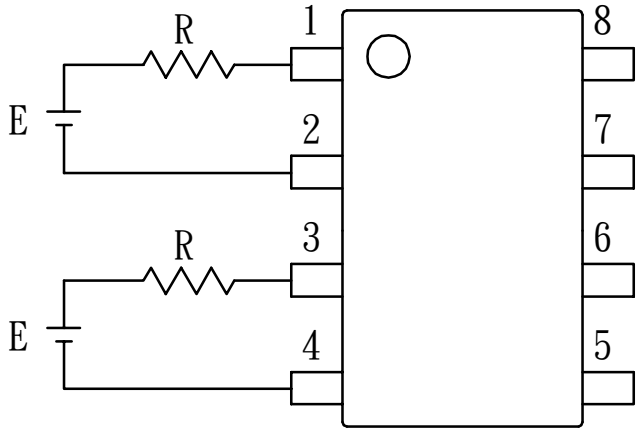
USING METHODS

Examples of resistance value to control LED forward current I_F

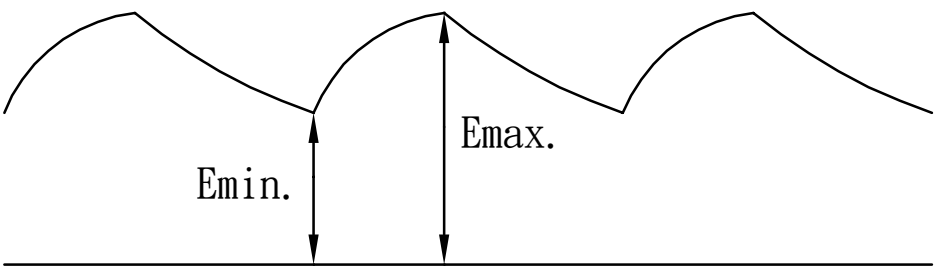
(I_F=5mA)



E	R
3.3V	Approx. 330 ohm
5V	Approx. 640 ohm
12V	Approx. 1.9K ohm
15V	Approx. 2.5K ohm
24V	Approx. 4.1K ohm

(1) LED forward current must be more than 5mA, at E min.

(2) LED forward current must be less than 50mA, at E max.



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COSMO ELECTRONICS CORPORATION	SOLID STATE RELAY-MOSFET OUTPUT KAQW212S	NO.62M20006	REV.
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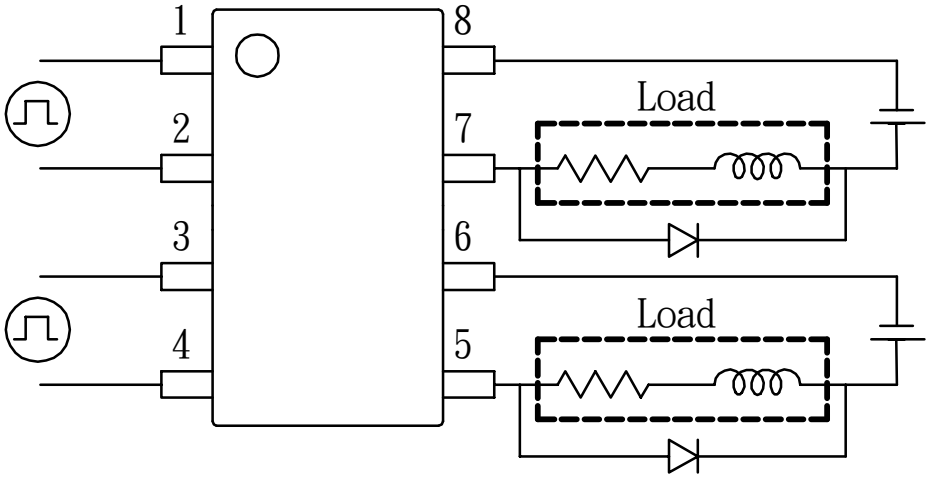
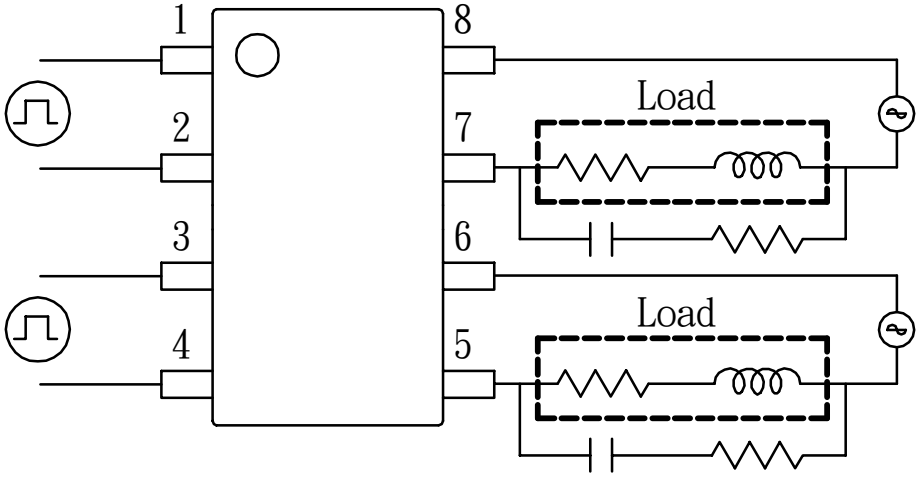
USING METHODS

Regulate the spike voltage generated on the inductive load as follows





R-C Snubber